

FEATURES

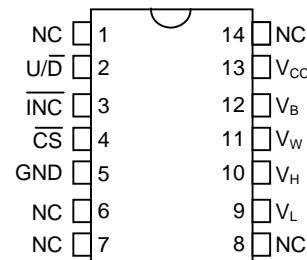
- 128 position, digitally controlled potentiometer
- Operates from a +5 volts power supply with TTL signal inputs
- Wide analog voltage range of ± 5 volts
- Low-power CMOS
- 14-pin DIP or 16-pin SOIC for surface mount applications
- Default position on power up sets wiper position to 10% of active digital taps (3% of the total end-to-end resistance)
- Operating temperature range
 - Industrial temp. range: -40°C to +85°C

Resistance/Step

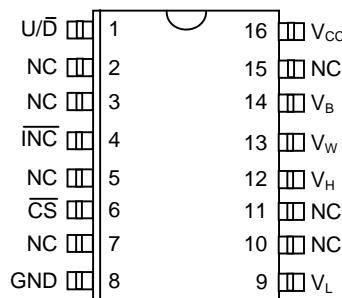
Resistance values	Low End	High End	-3dB Point
DS1666-10	10K	24Ω	152Ω
DS1666-50	50K	122Ω	759Ω
DS1666-100	100K	243Ω	1.519Ω

1.0 MHz 200 kHz 100 kHz

PIN ASSIGNMENT



14-PIN DIP (300 MIL)
 See Mech. Drawings Section



16-PIN SOIC (300 MIL)
 See Mech. Drawings Section

PIN DESCRIPTIONS

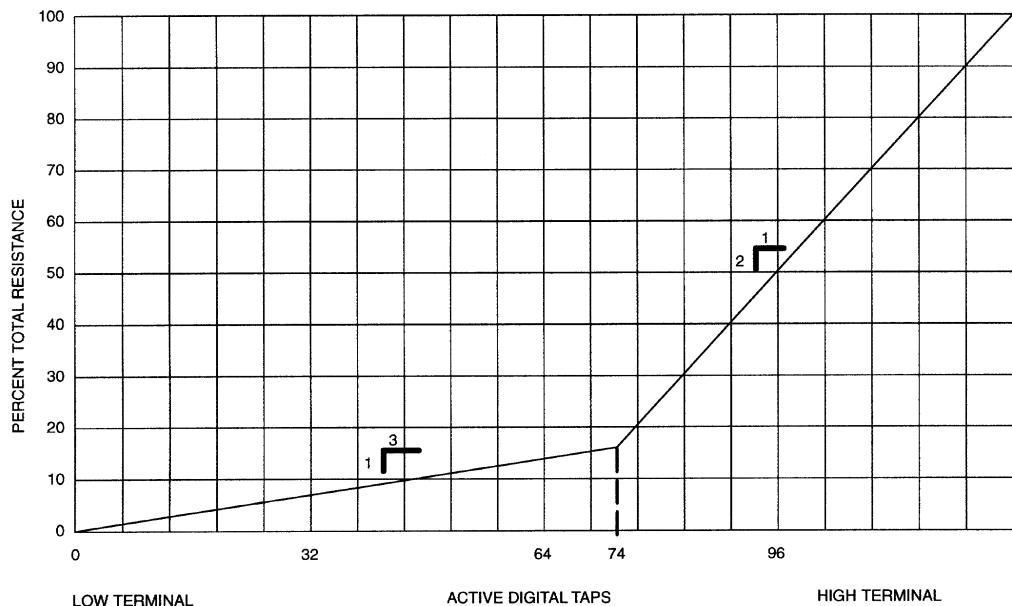
V_H	- High Terminal of Potentiometer
V_L	- Low Terminal of Potentiometer
V_W	- Wiper Terminal of Potentiometer
U/\bar{D}	- Up/Down Control
INC	- Wiper Movement Control
CS	- Chip Select for Wiper Movement
NC	- No Connection
V_{CC}	- 5V Power Supply Input
GND	- Ground
V_B	- Substrate Bias Voltage (0 to -5V)

DESCRIPTION

The DS1666 Audio Digital Resistor is a solid-state potentiometer composed of 127 digitally controlled resistive elements. Between each resistive section and both ends of the potentiometer are tap points multiplexed to the wiper. The position of the wiper on the resistance array is controlled by the \bar{CS} , U/\bar{D} and INC inputs. The taper of the DS1666 is shown in Figure 1.

The DS1666 is uniquely designed to provide a potentiometer that is pseudo-logarithmic rather than linear across its entire range. The lower half of the potentiometer advances 1% of total resistance for each 3% of scale advanced, providing for precise amplification of low volume signals. The upper half of the potentiometer advances 2% of resistance for every 1% of scale advanced, providing for the lower resolution gain required for high volume amplification.

GRAPH OF AUDIO TAPER Figure 1



OPERATION

The DS1666 has a total of 128 tap-points including the V_L and V_H terminals. A total of 127 resistive segments exist between the V_L and V_H terminals. These tap-points are accessible to the V_w terminal whose position is controlled via a 3-terminal control port. A block diagram of the DS1666 is shown in Figure 2.

The 3-terminal port of the DS1666 provides an increment/ decrement interface which is activated via a chip select input. This interface consists of the input signals \overline{CS} , \overline{INC} , and U/D . These input signals control a 7-bit up/down counter. The output of the 7-bit up/down counter controls a 1 of 128 decoder to select wiper position. The timing diagram for the 3-terminal interface control is shown in Figure 4.

ANALOG CHARACTERISTICS

The DS1666 has a pseudo-logarithmic resistor array that resembles an audio taper potentiometer as shown in Figure 1. Taps on the lower portion of the potentiometer increment 0.25% of the total resistance and are specified to within $\pm 0.5\%$ of the expected value. Taps on the higher portion increment 1.5% of the total resistance and are specified to within $\pm 2.0\%$ of the expected value.

End-to-End Resistance Tolerance = $\pm 20\%$
 Temperature Coefficient = 750 PPM/ $^{\circ}$ C typical

PIN DESCRIPTIONS

V_{CC} - Power Supply. The DS1666 will support supply voltages ranging from +4.5 to +5.5 volts.

GND - Ground Terminal.

V_B - Negative Bias. The DS1666 will support a negative bias ranging from 0 to -5 volts.

H - High-Terminal of Potentiometer. It is not required that this terminal be connected to a potential greater than the V_L terminal. Voltage applied to the V_H terminal can not exceed the power-supply voltage, (V_{CC}), or go below the negative bias, (V_B).

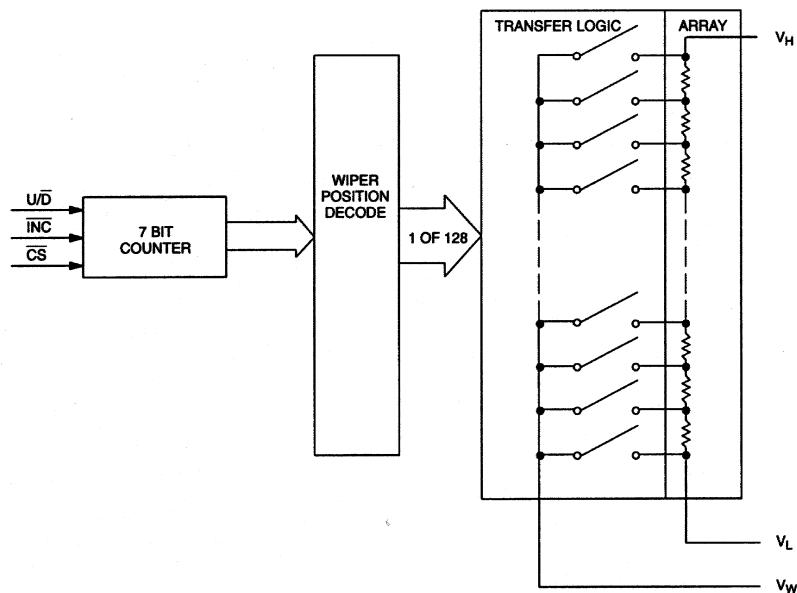
V_L - Low-Terminal of Potentiometer. It is not required that this terminal be connected to a potential less than the V_H terminal. Voltage applied to the V_L terminal cannot exceed the power-supply voltage, (V_{CC}), or go below the negative bias (V_B).

V_W - Wiper of the Potentiometer. Its position on the resistor array is controlled by the 3-terminal control port. Voltage applied to the wiper cannot exceed the power-supply voltage, V_{CC}, or go below the negative bias (V_B).

CS - Chip Select. The CS input is used to activate the control port of the DS1666. This input is active low. When in a high-state, activity on the INC and U/D port pins will not affect or change wiper position.

INC - Wiper Movement Control. This input provides for wiper position changes when the CS pin is low. Wiper position changes will occur one position per high-to-low transition of this input signal. Position changes will not occur if the CS pin is in a high-state.

U/D - Up/Down Control. This input sets the direction of wiper movement. When in a high-state and CS is low, any high-to-low transition on INC will cause a one position movement of the wiper towards the V_H terminal. When in a low-state and CS is low, any high-to-low transitions on INC will cause the position of the wiper to move towards the V_L terminal.

BLOCK DIAGRAM Figure 2**MODE SELECTION** Figure 3

\overline{CS}	\overline{INC}	U/D	MODE
L	—	H	WIPER UP
L	—	L	WIPER DOWN
H	X	X	INACTIVE

ABSOLUTE MAXIMUM RATINGS*

Voltage on \overline{CS} , \overline{INC} , U/\overline{D} and U/\overline{D} and V_{CC} Relative to Ground	-0.5V to +7.0V
Voltage on V_H , V_L and V_W Relative to Ground	-6.5V to +6.5V
Voltage on V_B	-6.5V to GND
Operating Temperature	-40° to +85°C
Storage Temperature	-55°C to +125°C
Soldering Temperature	260°C for 10 seconds

* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS (-40°C to +85°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	V_{CC}	+4.5	5.0	5.5	V	1
Input Logic 1	V_{IH}	2.0		$V_{CC}+0.5$	V	1
Input Logic 0	V_{IL}	-0.5		+0.8	V	1
V_H , V_L , V_W Voltage	V_R	$V_B-0.3$		$V_{CC}+0.3$	V	1, 3
V_B Voltage	V_B	-5.5		GND	V	1

DC ELECTRICAL CHARACTERISTICS (-40°C to +85°C; $V_{CC} = 5.0V \pm 10\%$)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Supply Current	I_{CC}		0.2	4.5	mA	4
Input Leakage	I_{LI}	-1		+1	μA	
Wiper Resistance	R_W		350	900	Ω	2
Wiper Current	I_W			1	mA	

CAPACITANCE ($t_A=25^\circ C$)

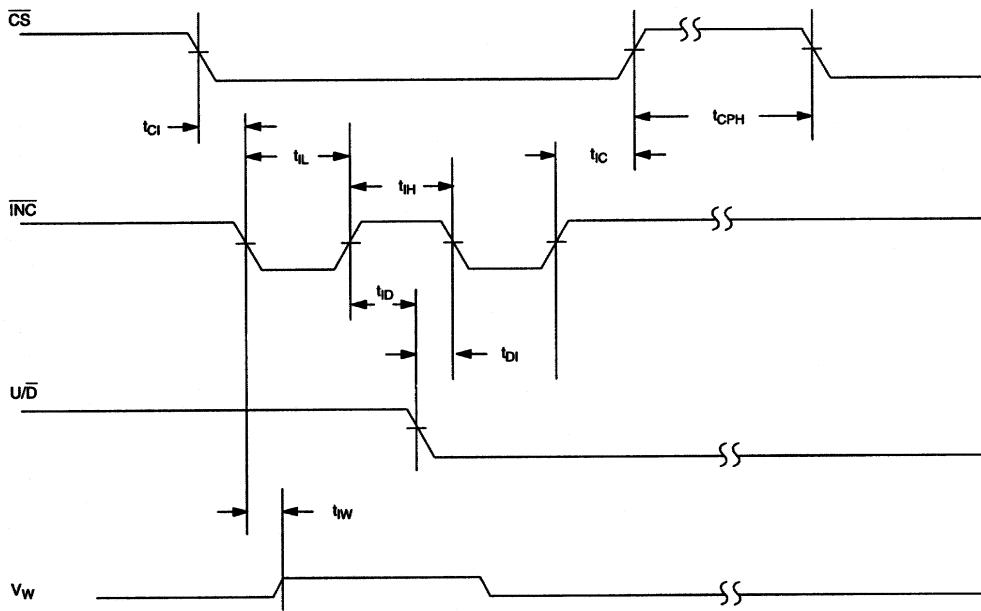
PARAMETER	SYMBOL	CONDITION	TYP	MAX	UNITS	NOTES
Capacitance	C_{IN}	$t_A=25^\circ C$	6		pF	

ANALOG RESISTOR CHARACTERISTICS (-40°C to +85°C; V_{CC} = 5.0V ± 10%)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Total Resistance “-10”			10		KΩ	5
“-50”			50		KΩ	5
“-100”			100		KΩ	5
End-to-End Resistor Tolerance		-20		+20	%	8
Absolute Tolerance Low End (0.25% Increments)		-0.5		+0.5	%	6
High End (1.5% Increments)		-2.0		+2.0	%	6
-3 dB Cutoff Frequency	f _{CUTOFF}				MHz	7
Temperature Coefficient			750		ppm/°C	

AC ELECTRICAL CHARACTERISTICS (-40°C to +85°C; V_{CC} = 5.0V ± 10%)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
CS to INC Setup	t _{CI}	100			ns	
INC High to U/D Change	t _{ID}	100			ns	
U/D to INC Setup	t _{DI}	1			μs	
INC Low Period	t _{IL}	500			ns	
INC High Period	t _{IH}	1			μs	
INC Low to Wiper Change	t _{IW}			200	ns	

AC TIMING Figure 4**NOTES:**

1. All Voltages are referenced to ground.
2. Typical Values are for $T_A=25^\circ\text{C}$ and nominal supply voltages.
3. Resistors input voltages cannot go below V_B or exceed V_{CC} by the amounts shown.
4. Maximum current specifications are based on the clock rate of $\overline{\text{INC}}$ input. This specification represents the current required when changing the wiper position.
5. The DS1666 is available in three end-to-end resistor values. These include $10\text{K}\Omega$ for the DS1666-10; $50\text{K}\Omega$ for the DS1666-50; and $100\text{K}\Omega$ for the DS1666-100.
6. Absolute tolerance is used to compare measured wiper voltage versus expected wiper voltage as determined by wiper position.
7. -3dB cutoff frequency characteristics for the DS1666 depend on potentiometer total resistance. The DS1666-10 is 1 MHz; the DS1666-50 is 200 KHz; and the DS1666-100 is 100 KHz.
8. Valid at 25°C only

AC TEST CONDITIONS

Input Pulse Levels 0V to 3V

Input Rise and Fall Times 10 ns

DS1666 ORDERING INFORMATION

ORDERING NUMBER	PACKAGE	OPERATING TEMPERATURE	VERSION
DS1666-010	14L DIP	-40°C TO +85°C	10 kΩ
DS1666-050	14L DIP	-40°C TO +85°C	50 kΩ
DS1666-100	14L DIP	-40°C TO +85°C	100 kΩ
DS1666S-010*	16L SOIC (300-mil)	-40°C TO +85°C	10 kΩ
DS1666S-050*	16L SOIC (300-mil)	-40°C TO +85°C	50 kΩ
DS1666S-100*	16L SOIC (300-mil)	-40°C TO +85°C	100 kΩ

* Add “/T & R” for tape and reel packaging.

DATA SHEET REVISION SUMMARY

The following represent the key differences between 07/26/93 and 06/18/97 version of the DS1666 data sheet. Please review this summary carefully.

1. Remove commercial temp grade reference.
2. Add order info table.
3. Improve operating description and add “ANALOG Resistor CHARACTERISTICS”.